



### **Product Summary**

V <sub>(BR)DSS</sub>	Max R <sub>DS(ON)</sub>	Max I <sub>D</sub> T <sub>A</sub> = +25°C (Note 7)
60V	250mΩ @ V <sub>GS</sub> = 10V	1.4A
000	350mΩ @ V <sub>GS</sub> = 4.5V	1.2A

## Description

This MOSFET utilizes a unique structure that combines the benefits of low on-resistance with a fast switching speed, making it ideal for high-efficiency power management applications.

# **Applications**

- **DC-DC Converters**
- **Power Management Functions**
- Relay And Solenoid Driving
- Motor Control

### 60V N-CHANNEL ENHANCEMENT MODE MOSFET

### **Features**

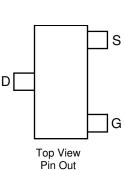
- Low On-Resistance
- Fast Switching Speed
- Low Threshold
- Low Gate Charge
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- **PPAP Capable (Note 4)**

# **Mechanical Data**

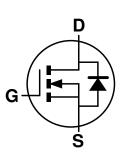
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish @3
- Weight: 0.008 grams (Approximate)



Top View



SOT23



Equivalent Circuit

### Ordering Information (Notes 4 & 5)

h					
Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXMN6A07FTA	AEC-Q101	7N6	7	8	3,000
ZXMN6A07FQTA	Automotive	7N6	7	8	3,000

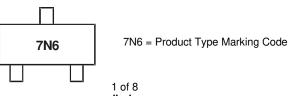
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-Free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.

5. For packaging details, go to our website at http"//www.diodes.com/products/packages.html.

# Marking Information





### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic				Symbol	Value	Units
Drain-Source Voltage				V <sub>DSS</sub>	60	V
Gate-Source Voltage				V <sub>GS</sub>	±20	V
Continuous Drain Current	V <sub>GS</sub> = 10V	$T_{A} = +70^{\circ}C$ (N	lote 7) lote 7) lote 6)	Ι <sub>D</sub>	1.4 1.1 1.2	А
Pulsed Drain Current (Note 8)				I <sub>DM</sub>	6.9	А
Continuous Source Current (Body Diode) (Note 7)				Is	1	A
Pulsed Source Current (Body Diode) (Note 8)				I <sub>SM</sub>	6.9	А

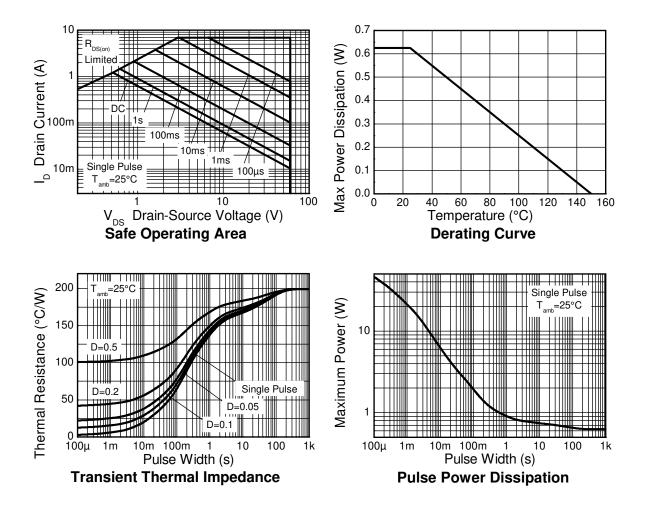
# **Thermal Characteristics**

Characteristic	Symbol	Value	Unit	
Power Dissipation (Note 6) Linear Derating Factor		P <sub>D</sub>	625 5	mW mW/°C
Power Dissipation (Note 7) Linear Derating Factor		PD	806 6.4	mW mW/°C
Thermal Resistance, Junction to Ambient (Note 6) (Note 7)		R <sub>0JA</sub>	200 155	°C/W
Thermal Resistance, Junction to Ambient (Note 9)		R <sub>ejl</sub>	194	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

6. For a device surface mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
7. For a device surface mounted on FR4 PCB measured at t ≤5 secs.
8. Repetitive rating 25mm x 25mm FR4 PCB, D=0.02 pulse width=300µs - pulse current limited by maximum junction temperate.
9. Thermal resistance from junction to solder-point (at the end of the drain lead). Notes:



# Thermal Characteristics (continued)





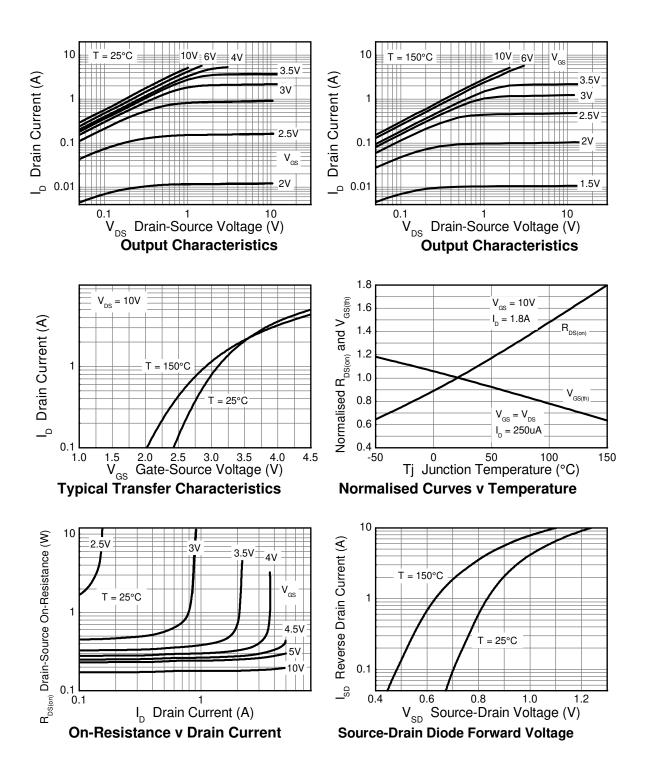
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS			-				
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	—	—	V	$I_D = 250 \mu A$ , $V_{GS} = 0 V$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	1	μΑ	$V_{DS} = 60V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS							
Gate Threshold Voltage	V <sub>GS(th)</sub>	1.0	_	3.0	V	$I_D = 250 \mu A$ , $V_{DS} = V_{GS}$	
Statia Drain Source On Desistance (Note 10)				0.250	Ω	$V_{GS} = 10V, I_D = 1.8A$	
Static Drain-Source On-Resistance (Note 10)	R <sub>DS(ON)</sub>	_	_	0.350	Ω	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 1.3A	
Forward Transconductance (Notes 10 and 12)	<b>g</b> fs	_	2.3	_	S	V <sub>DS</sub> = 15V, I <sub>D</sub> = 1.8A	
Diode Forward Voltage (Note 10)	V <sub>SD</sub>	_	0.8	0.95	V	T <sub>J</sub> = +25°C, I <sub>S</sub> = 0.45A, V <sub>GS</sub> = 0V	
Reverse Recovery Time (Note 12)	t <sub>rr</sub>	_	20.5	_	ns	T <sub>J</sub> = +25°C, I <sub>F</sub> = 1.8A, di/dt = 100A/μs	
Reverse Recovery Charge (Note 12)	Q <sub>rr</sub>		21.3		nC		
DYNAMIC CHARACTERISTICS (Note 12)			•			·	
Input Capacitance	C <sub>iss</sub>	_	166	_		$V_{DD} = 40V, V_{GS} = 0V$ f = 1.0MHz	
Output Capacitance	C <sub>oss</sub>	_	19.5	_	pF		
Reverse Transfer Capacitance	Crss	_	8.7	_			
Turn-On Delay Time (Note 11)	t <sub>D(on)</sub>	_	1.8	_			
Turn-On Rise Time (Note 11)	tr	_	1.4	_		$\label{eq:VDD} \begin{array}{l} V_{DD}=30V,\ I_D=1.8A,\\ R_G\cong 6.0\Omega,\ V_{GS}=10V \end{array}$	
Turn-Off Delay Time (Note 11)	t <sub>D(off)</sub>	_	4.9	_	ns		
Turn-Off Fall Time (Note 11)	t <sub>f</sub>		2.0				
Total Gate Charge (Note 11)	Qg	_	1.65	_	nC	$V_{DS} = 30V, V_{GS} = 5V,$ $I_{D} = 1.8A$	
Total Gate Charge (Note 11)	Qa	_	3.2	_			
Gate-Source Charge (Note 11)	Q <sub>gs</sub>	_	0.67	_	nC	$V_{DS} = 30V, V_{GS} = 10V,$	
Gate-Drain Charge (Note 11)	Q <sub>gd</sub>	_	0.82			I <sub>D</sub> = 1.8A	

 Measured under pulsed conditions. Pulse width = 300µs. Duty cycle ≤ 2%.
 Switching characteristics are independent of operating junction temperature.
 For design aid only, not subject to production testing. Notes:

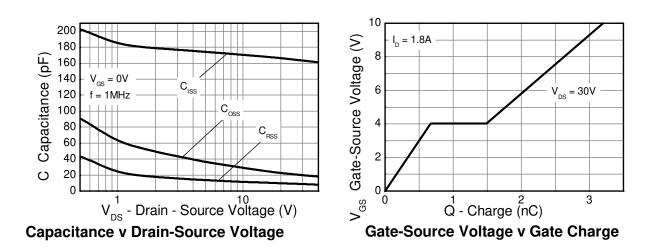


# **Typical Characteristics**

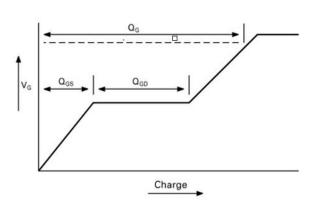




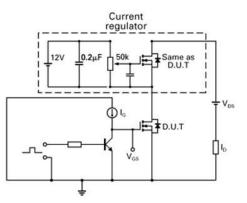
## Typical Characteristics (continued)



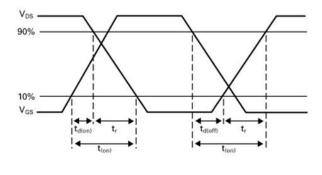
**Test Circuits** 



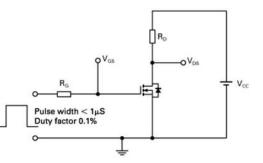
Basic gate charge waveform



Gate charge test circuit



Switching time waveforms

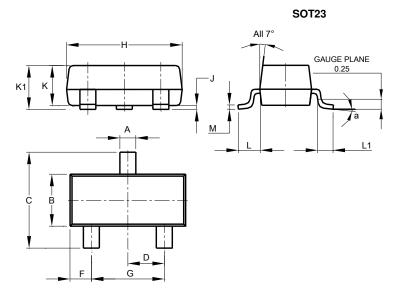


# Switching time test circuit



# Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

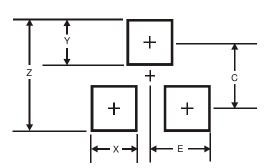


SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
в	1.20	1.40	1.30		
C	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
K	0.890	1.00	0.975		
K1	0.903	1.10	1.025		
L	0.45	0.61	0.55		
L1	0.25	0.55	0.40		
М	0.085	0.150	0.110		
а	8°				
All Dimensions in mm					

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

SOT23



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35

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